

isc Silicon NPN Power Transistor
2SD843
DESCRIPTION

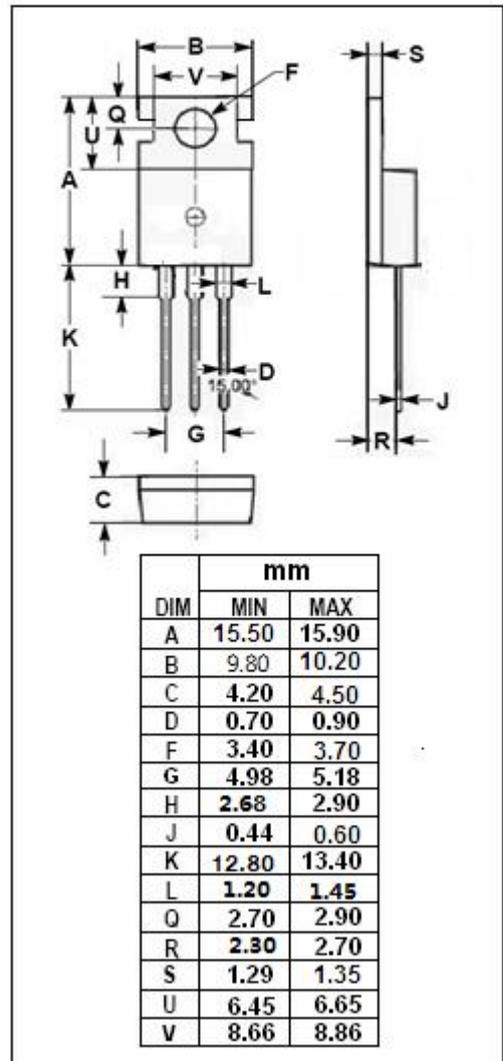
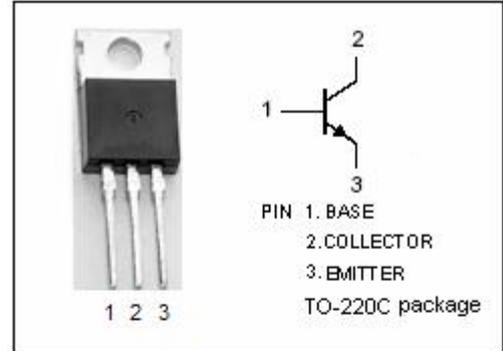
- High Collector Current: $I_C = 7A$
- Low Collector Saturation Voltage
: $V_{CE(sat)} = 0.5V(\text{Max}) @ I_C = 4A$
- High Collector Power Dissipation
- Complement to Type 2SB753
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- High current switching applications
- Power amplifier applications.

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	100	V
V_{CEO}	Collector-Emitter Voltage	80	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current-Continuous	7	A
P_C	Collector Power Dissipation @ $T_a = 25^\circ\text{C}$	1.5	W
	Total Power Dissipation @ $T_c = 25^\circ\text{C}$	40	
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55~150	$^\circ\text{C}$



isc Silicon NPN Power Transistor**2SD843****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C= 10\text{mA}$; $I_B= 0$	80			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C= 4\text{A}$; $I_B= 0.4\text{A}$		0.25	0.5	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C= 4\text{A}$; $I_B= 0.4\text{A}$		0.9	1.4	V
I_{CBO}	Collector Cutoff Current	$V_{CB}= 100\text{V}$; $I_E= 0$			5	μA
I_{EBO}	Emitter Cutoff Current	$V_{EB}= 5\text{V}$; $I_C= 0$			5	μA
h_{FE-1}	DC Current Gain	$I_C= 1\text{A}$; $V_{CE}= 1\text{V}$	70		240	
h_{FE-2}	DC Current Gain	$I_C= 4\text{A}$; $V_{CE}= 1\text{V}$	30			
f_T	Current-Gain—Bandwidth Product	$I_C= 1\text{A}$; $V_{CE}= 4\text{V}$		10		MHz
C_{OB}	Output Capacitance	$I_E= 0$; $V_{CB}= 10\text{V}$; $f_{test}= 1\text{MHz}$		250		pF

Switching times

t_{on}	Turn-on Time	$R_L= 10\ \Omega$, $V_{CC}= 30\text{V}$ $I_{B1}= I_{B2}= 0.3\text{A}$		0.4		μs
t_{stg}	Storage Time			2.5		μs
t_f	Fall Time			0.5		μs

◆ **h_{FE-1} Classifications**

O	Y
70-140	120-240

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